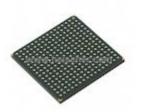




70T651S10BCI8 Information



For Reference Only

Part Number 70T651S10BCI8

Manufacturer IDT, Integrated Device Technology Inc

Category Integrated Circuits (ICs)

Memory

Description IC SRAM 9MBIT 10NS 256CABGA

Package 256-LBGA

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









70T651S10BCI8 Specifications

Manufacturer Part Number	70T651S10BCI8
Manufacturer	IDT, Integrated Device Technology Inc
Category	Integrated Circuits (ICs)
	Memory
Package	256-LBGA
Series	-
Memory Type	Volatile
Memory Format	SRAM
Technology	SRAM - Dual Port, Asynchronous
Memory Size	9Mb (256K x 36)
Memory Interface	Parallel
Clock Frequency	-
Write Cycle Time - Word, Page	10ns
Access Time	10ns
Voltage - Supply	2.4 V ~ 2.6 V
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	256-LBGA
Supplier Device Package	256-CABGA (17x17)
	Report errors

70T651S10BCI8 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

70T651S10BCI8 Payment Methods



















70T651S10BCI8 Shipping Methods













If you have any question about 70T651S10BCI8, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com